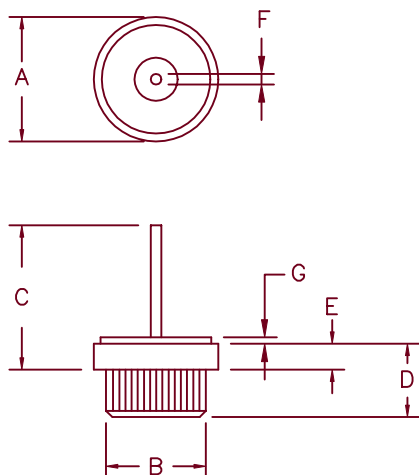


50 Amp Schottky Rectifier

SBR5090PF — SBR50100PF



Dim.	Inches		Millimeter		Notes
	Minimum	Maximum	Minimum	Maximum	
A	.590	.630	14.98	16.00	Dia.
B	.499	.510	12.67	12.95	Dia.
C	1.15	1.40	29.21	15.20	
D	.320	.350	8.12	8.89	
E	.090	.096	2.29	2.44	
F	.047	.055	1.19	1.40	Dia.
G	.020	.038	.510	.970	

Microsemi Catalog Number	Working Peak Reverse Voltage	Repetitive Peak Reverse Voltage
SBR5090PF*	90V	90V
SBR50100PF*	100V	100V

* Add Suffix R for Reverse Polarity

- Schottky Barrier Rectifier
- Guard Ring Protected
- 175°C Junction Temperature
- VRRM – 90 to 100 Volts
- Reverse Energy Tested

Electrical Characteristics

Average forward current	$I_F(AV)$ 50 Amps	$T_C = 136^\circ C$, Square wave, $R_{\theta JC} = 1.0^\circ C/W$ 8.3 ms, half sine, $T_J = 175^\circ C$ $f = 1$ KHz, $25^\circ C$, 1 μ sec Square wave
Maximum surge current	I_{FSM} 800 Amps	
Max repetitive peak reverse current	$I_R(OV)$ 1 Amps	$I_{FM} = 60A$; $T_J = 25^\circ C^*$
Max peak forward voltage	V_{FM} .89 Volts	
Max peak reverse current	I_{RM} 10 mA	V_{RRM} , $T_J = 125^\circ C^*$ V_{RRM} , $T_J = 25^\circ C$
Max peak reverse current	I_{RM} 1 mA	
Typical junction capacitance	C_J 1300 pF	$V_R = 5.0V$, $T_J = 25^\circ C$

*Pulse test: Pulse width 300 μ sec, Duty cycle 2%

Thermal and Mechanical Characteristics

Storage temp range	T_{STG}	$-55^\circ C$ to $175^\circ C$
Operating junction temp range	T_J	$-55^\circ C$ to $175^\circ C$
Max thermal resistance	$R_{\theta JC}$	$1.0^\circ C/W$ Junction to case
Weight		.32 ounces (9.2 grams) typical

SBR5090PF — SBR50100PF

Figure 1
Typical Forward Characteristics

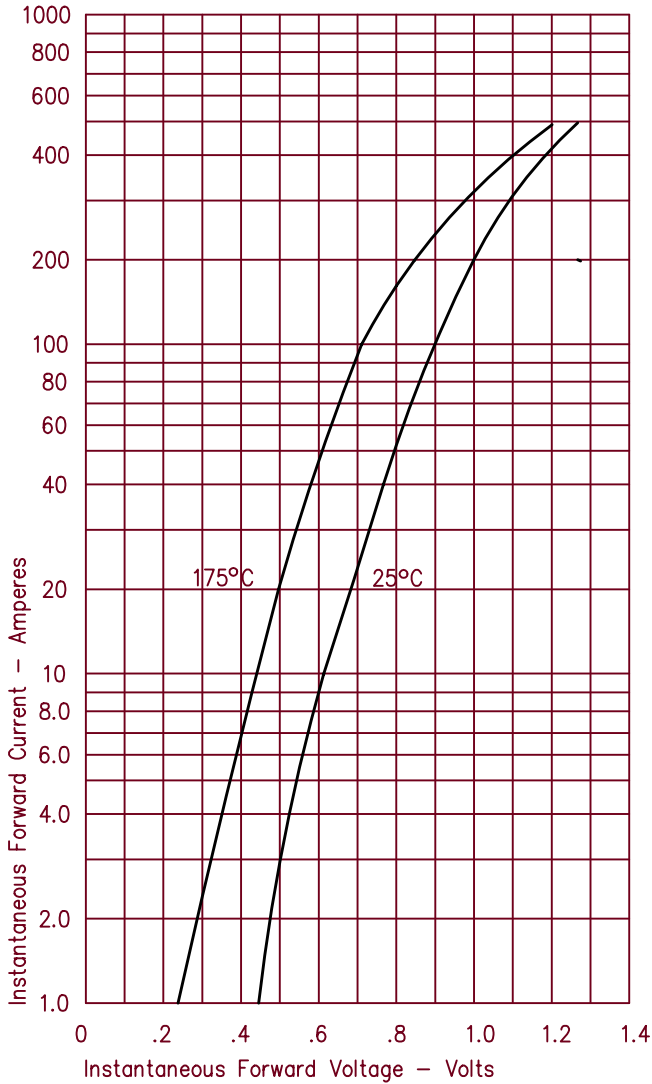


Figure 3
Typical Junction Capacitance

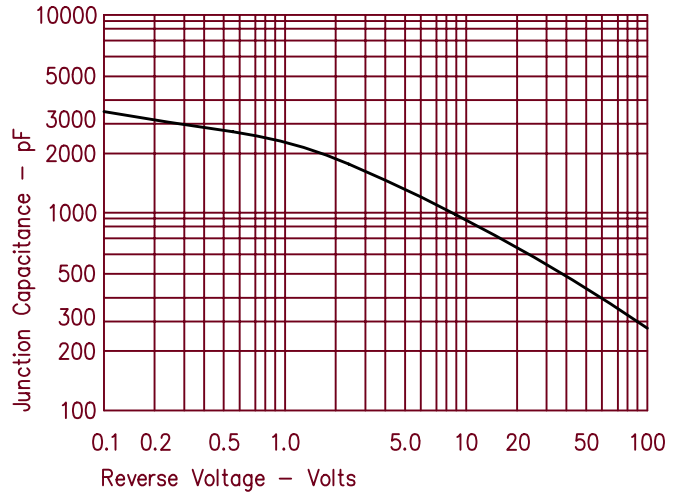


Figure 4
Forward Current Derating

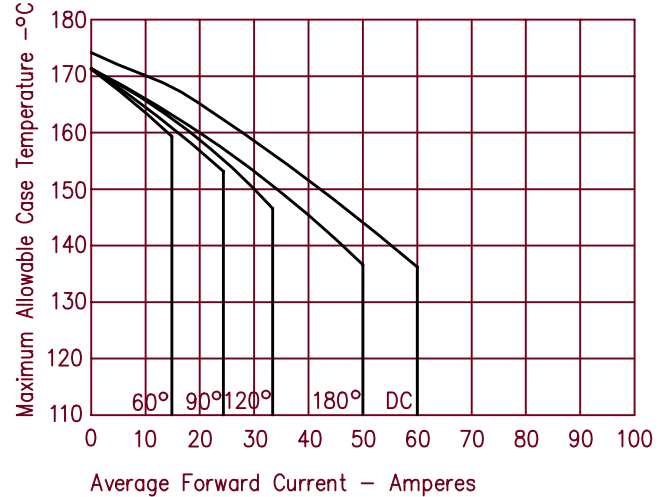


Figure 2
Typical Reverse Characteristics

